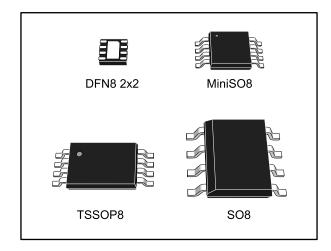


LM158, LM258, LM358

Low-power dual operational amplifiers

Datasheet - production data



Features

- Frequency compensation implemented internally
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1.1 MHz (temperature compensated)
- Very low supply current per channel essentially independent of supply voltage
- Low input bias current: 20 nA (temperature compensated)
- Low input offset voltage: 2 mV
- Low input offset current: 2 nA
- Input common-mode voltage range includes negative rails
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0 V to (V_{CC}⁺ - 1.5 V)

Related products

See LM158W for enhanced ESD ratings

Description

These circuits consist of two independent, highgain, internally frequency-compensated op amps, specifically designed to operate from a single power supply over a wide range of voltages. The low-power supply drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits, which can now be more easily implemented in single power supply systems. For example, these circuits can be directly supplied with the standard 5 V, which is used in logic systems and will easily provide the required interface electronics with no additional power supply.

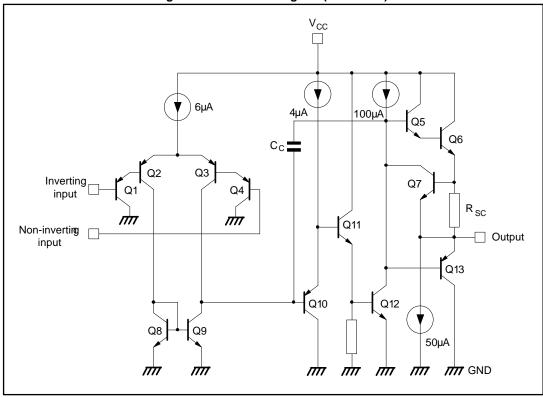
In linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

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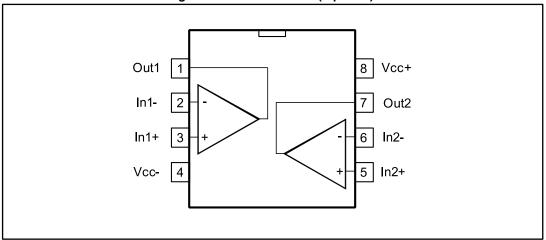
1 Schematic diagram

Figure 1: Schematic diagram (1/2 LM158)



2 Package pin connections

Figure 2: Pin connections (top view)



1. The exposed pad of the DFN8 2x2 can be left floating or connected to ground

3 Absolute maximum ratings

Table 1: Absolute maximum ratings

Symbol	Parameter		LM158,A	LM258,A	LM358,A	Unit	
V _{CC}	Supply voltage		±16 or 32				
Vi	Input voltage			32		V	
V _{id}	Differential input voltage			32			
	Output short-circuit duration (1)			Infinite			
l _{in}	Input current (2)	_	n DC or 50 mA ycle = 10 %, T	_	mA		
T _{oper}	Operating free-air temperature range	;	-55 to 125	-40 to 105	0 to 70		
T _{stg}	Storage temperature range	Storage temperature range			-65 to 150		
Tj	Maximum junction temperature		150				
		SO8	125				
Б	Thermal resistance junction to ambient ⁽³⁾	MiniSO8	190				
R_{thja}		DFN8 2x2	57				
	TSSOPE		120			°C/W	
		SO8		40			
R_{thjc}	Thermal resistance junction to case (3)	MiniSO8		39			
	Case	37					
	HBM: human body model ⁽⁴⁾			300			
ESD	MM: machine model (5)	200			- V		
	CDM: charged device model (6)	1.5			kV		

⁽¹⁾Short-circuits from the output to V_{CC} can cause excessive heating if $V_{CC} > 15$ V. The maximum output current is approximately 40 mA independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short circuits on all amplifiers.

 $^{^{(2)}}$ This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward-biased and thereby acting as input diode clamp. In addition to this diode action, there is NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the op amps to go to the V_{CC} voltage level (or to ground for a large overdrive) for the time during which an input is driven negative. This is not destructive and normal output is restored for input voltages above -0.3 V.

 $^{^{(3)}}$ Short-circuits can cause excessive heating and destructive dissipation. R_{th} are typical values.

⁽⁴⁾Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a 1.5 k Ω resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.

 $^{^{(5)}}$ Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω). This is done for all couples of connected pin combinations while the other pins are floating.

⁽⁶⁾Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

Table 2: Operating conditions

Symbol	Parameter		Value	Unit
V _{CC}	Supply voltage		3 to 30	V
V _{icm}	Common mode input voltage range (1)		(V_{CC}^{-}) - 0.3 to (V_{CC}^{+}) - 1.5	V
		LM158	-55 to 125	
T _{oper}	Operating free air temperature range	LM258	-40 to 105	°C
		LM358	0 to 70	

⁽¹⁾When used in comparator, the functionality is guaranteed as long as at least one input remains within the operating common mode voltage range.

4 Electrical characteristics

Table 3: Electrical characteristics for VCC+ = 5 V, VCC- = Ground, Vo = 1.4 V, Tamb = 25 $^{\circ}$ C (unless otherwise specified)

Symbol		Parameter	Min.	Тур.	Max.	Unit
		LM158A			2	
	(1)	LM258A, LM358A		1	3	
	Input offset voltage (1)	LM158, LM258			5	
V_{io}		LM358		2	7	mV
		LM158A, LM258A, LM358A			4	
	$T_{min} \le T_{amb} \le T_{max}$	LM158, LM258			7	
		LM358			9	
A)/ /AT	lancet offerst voltage duit	LM158A, LM258A, LM358A		7	15	//90
ΔV _{io} /ΔT	Input offset voltage drift	LM158, LM258, LM358		7	30	μV/°C
	long offeet ourrent	LM158A, LM258A, LM358A		2	10	
,	Input offset current	LM158, LM258, LM358		2	30	^
l _{io}	T .T .T	LM158A, LM258A, LM358A			30	nA
	$T_{min} \le T_{amb} \le T_{max}$	LM158, LM258, LM358			40	
A1 /AT	lancet offers accomment duits	LM158A, LM258A, LM358A		10	200	pA/°C
$\Delta I_{io}/\Delta T$	Input offset current drift	LM158, LM258, LM358		10	300	
	Input bias current (2)	LM158A, LM258A, LM358A		20	50	
,		LM158, LM258, LM358		20	150	^
l _{ib}	$T_{min} \le T_{amb} \le T_{max}$	LM158A, LM258A, LM358A			100	nA
		LM158, LM258, LM358			200	
A_{vd}	Large signal voltage	$V_{CC}^{+} = 15 \text{ V}, R_L = 2 \text{ k}\Omega,$ $V_o = 1.4 \text{ V} \text{ to } 11.4 \text{ V}$	50	100		V/mV
	gain	$T_{min} \le T_{amb} \le T_{max}$	25			
C) (D	Supply voltage rejection	V_{CC}^+ = 5 V to 30 V, $R_s \le 10 \text{ k}\Omega$	65	100		10
SVR	ratio	$T_{min} \le T_{amb} \le T_{max}$	65			dB
	Supply current, all amp,	$T_{min} \le T_{amb} \le T_{max} V_{CC}^+ = 5 V$		0.7	1.2	A
I _{CC}	no load	$T_{min} \le T_{amb} \le T_{max} V_{CC}^+ = 30 V$			2	mA
V	Input common mode	$V_{CC}^{+}=30 \text{ V}^{(3)}$	0		(V _{CC} ⁺) - 1.5	V
V_{icm}	voltage range	$T_{min} \le T_{amb} \le T_{max}$	0		(V _{CC} ⁺) - 2	V
CMR	Common mode	$R_s \le 10 \text{ k}\Omega$	70	85		dB
CIVIR	rejection ratio	$T_{min} \le T_{amb} \le T_{max}$	60			ub
I _{source}	Output current source	$V_{CC}^{+} = 15 \text{ V}, V_{o} = 2 \text{ V}, V_{id} = 1 \text{ V}$	20	40	60	mA
1.	Output sink surrent	$V_{CC}^{+} = 15 \text{ V}, V_{o} = 2 \text{ V}, V_{id} = -1 \text{ V}$	10	20		mA
I _{sink}	Output sink current	$V_{CC}^{+} = 15 \text{ V}, V_{o} = 0.2 \text{ V}, V_{id} = -1 \text{ V}$	12	50		μA

Electrical characteristics

LM158, LM258, LM358

Symbol		Parameter	Min.	Тур.	Max.	Unit
		$R_L = 2 k\Omega, V_{CC}^+ = 30 V$	26	27		
	High level output	$T_{min} \le T_{amb} \le T_{max}$	26			V
V _{OH}	voltage	$R_L = 10 \text{ k}\Omega, V_{CC}^+ = 30 \text{ V}$	27	28		V
		$T_{min} \le T_{amb} \le T_{max}$	27			
	Law law law a law to walto a	$R_L = 10 \text{ k}\Omega$		5	20	\/
V _{OL}	Low level output voltage	$T_{min} \le T_{amb} \le T_{max}$			20	mV
SR	Slew rate	$V_{CC}^{+} = 15 \text{ V}, V_{i} = 0.5 \text{ to } 3 \text{ V},$ $R_{L} = 2 \text{ k}\Omega, C_{L} = 100 \text{ pF}, \text{ unity gain}$	0.3	0.6		V/µs
GBP	Gain bandwidth product	$V_{CC}^{+} = 30 \text{ V, f} = 100 \text{ kHz,}$ $V_{in} = 10 \text{ mV, R}_{L} = 2 \text{ k}\Omega, C_{L} = 100 \text{ pF}$	0.7	1.1		MHz
THD	Total harmonic distortion	$ f = 1 \text{ kHz, } A_v = 20 \text{ dB, } R_L = 2 \text{ k}\Omega, \\ V_o = 2 \text{ V}_{pp}, \ C_L = 100 \text{ pF, } V_O = 2 \text{ V}_{pp} $		0.02		%
e _n	Equivalent input noise voltage	f = 1 kHz, R_s = 100 Ω, V_{CC}^+ = 30V		55		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
V _{o1} /V _{o2}	Channel separation (4)	1kHz ≤ f ≤ 20 kHz		120		dB

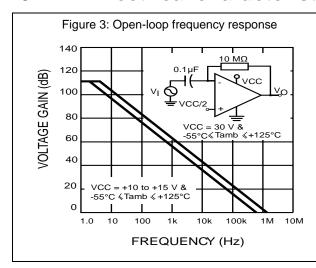
 $^{^{(1)}}$ Vo = 1.4 V, Rs = 0 Ω , 5 V < VCC + < 30 V, 0 < Vic < VCC + - 1.5 V

⁽²⁾The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so there is no change in the load on the input lines.

⁽³⁾The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is (V_{CC}^{+}) - 1.5 V, but either or both inputs can go to 32 V without damage.

Due to the proximity of external components, ensure that stray capacitance between these external parts does not cause coupling. Typically, this can be detected because this type of capacitance increases at higher frequencies.

5 Electrical characteristic curves



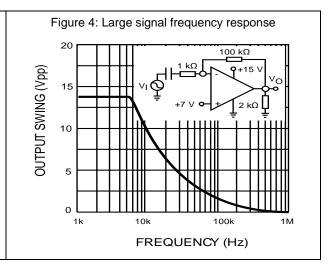
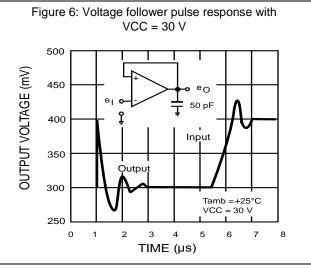
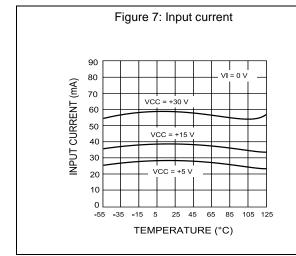


Figure 5: Voltage follower pulse response with VCC = 15 V

A TIME (µs)





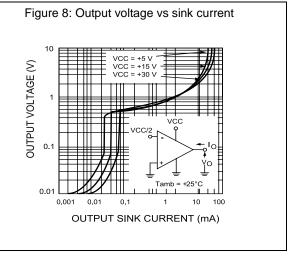
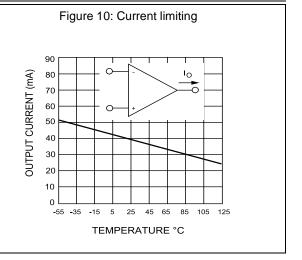


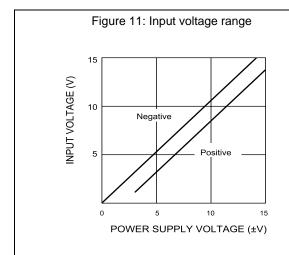
Figure 9: Output voltage vs source current

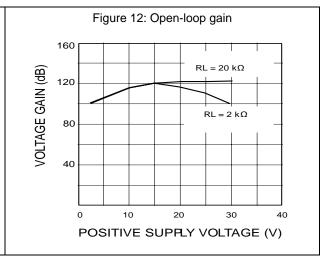
8
7
4
VCC/2

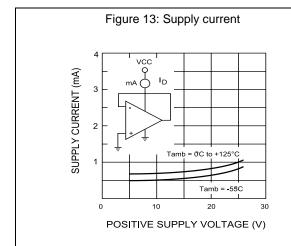
V

OUTPUT SOURCE CURRENT (mA)









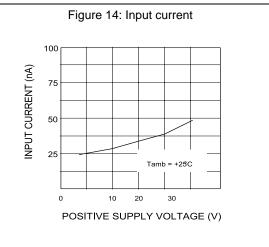
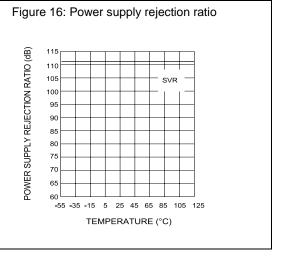
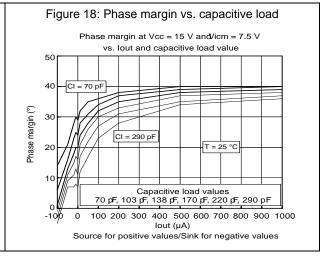


Figure 15: Gain bandwidth product

1.5
1.35
1.35
1.05
1.05
0.9
0.75
0.6
0.45
0.45
0.45
0.45
0.55 -35 -15 5 25 45 65 85 105 125

TEMPERATURE (°C)





6 Typical applications

Single supply voltage $V_{CC} = 5 V_{DC}$.

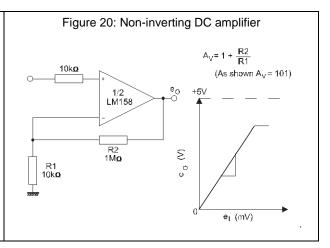


Figure 21: AC-coupled non-inverting amplifier

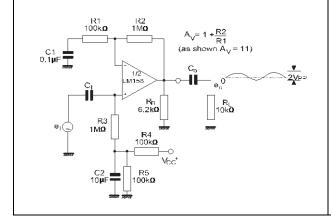
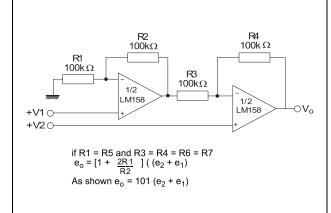


Figure 22: DC summing amplifier $e_1 = \frac{100k\Omega}{100k\Omega}$ $e_2 = \frac{100k\Omega}{100k\Omega}$ $e_3 = \frac{100k\Omega}{100k\Omega}$ $e_4 = \frac{100k\Omega}{100k\Omega}$ where $(e1 + e_2) \ge (e_3 + e_4)$ to keep $e_0 \ge 0$ V

Figure 23: High input Z, DC differential amplifier



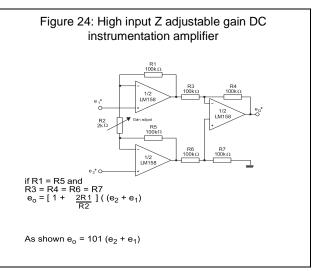
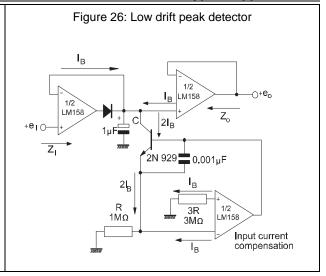
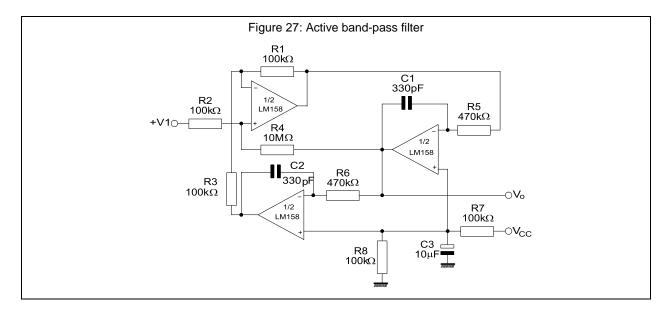


Figure 25: Using symmetrical amplifiers to reduce input current 1/2 -⊝ e_o LM158 $I_1 \downarrow I_B$ +e₁○-I_B 2N 929 **=**0.001μF I_B I_{B} 1/2 LM158 ЗМΩ Input current compensation IB 1.5ΜΩ





7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

7.1 SO8 package information

D hx45°

SEATING PLANE

C GAGE PLANE

Figure 28: SO8 package outline

Table 4: SO8 mechanical data

	Dimensions							
Ref.	Millimeters							
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.75			0.069		
A1	0.10		0.25	0.004		0.010		
A2	1.25			0.049				
b	0.28		0.48	0.011		0.019		
С	0.17		0.23	0.007		0.010		
D	4.80	4.90	5.00	0.189	0.193	0.197		
E	5.80	6.00	6.20	0.228	0.236	0.244		
E1	3.80	3.90	4.00	0.150	0.154	0.157		
е		1.27			0.050			
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
L1		1.04			0.040			
k	1°		8°	1°		8°		
ccc			0.10			0.004		

MiniSO8 package information 7.2

A □ ccc C SEATING PLANE С

Figure 29: MiniSO8 package outline

Table 5: MiniSO8 mechanical data

	Dimensions						
Ref.	Millimeters						
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.1			0.043	
A1	0		0.15	0		0.006	
A2	0.75	0.85	0.95	0.030	0.033	0.037	
b	0.22		0.40	0.009		0.016	
С	0.08		0.23	0.003		0.009	
D	2.80	3.00	3.20	0.11	0.118	0.126	
Е	4.65	4.90	5.15	0.183	0.193	0.203	
E1	2.80	3.00	3.10	0.11	0.118	0.122	
е		0.65			0.026		
L	0.40	0.60	0.80	0.016	0.024	0.031	
L1		0.95			0.037		
L2		0.25			0.010		
k	0°		8°	0°		8°	
ccc			0.10			0.004	

7.3 DFN8 2 x 2 package information

Figure 30: DFN8 2 x 2 package outline

Table 6: DFN8 2 x 2 mechanical data

			Dimer	nsions		
Ref.	Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	0.51	0.55	0.60	0.020	0.022	0.024
A1			0.05			0.002
А3		0.15			0.006	
b	0.18	0.25	0.30	0.007	0.010	0.012
D	1.85	2.00	2.15	0.073	0.079	0.085
D2	1.45	1.60	1.70	0.057	0.063	0.067
Е	1.85	2.00	2.15	0.073	0.079	0.085
E2	0.75	0.90	1.00	0.030	0.035	0.039
е		0.50			0.020	
L			0.425			0.017
ddd			0.08			0.003

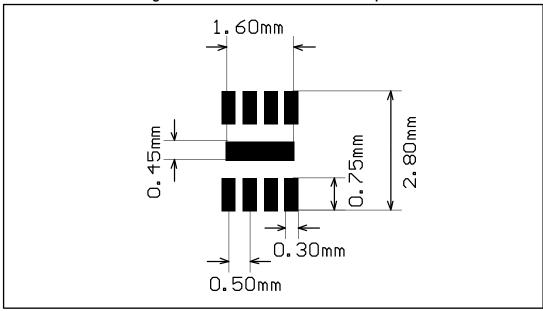


Figure 31: DFN8 2 x 2 recommended footprint

7.4 TSSOP8 package information

PIN 1 IDENTIFICATION

PLANE

SEATING

PLANE

PLANE

COMMITTER

CATION

PLANE

COMMITTER

Figure 32: TSSOP8 package outline

Table 7: TSSOP8 mechanical data

	Dimensions							
Ref.	Millimeters							
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.2			0.047		
A1	0.05		0.15	0.002		0.006		
A2	0.80	1.00	1.05	0.031	0.039	0.041		
b	0.19		0.30	0.007		0.012		
С	0.09		0.20	0.004		0.008		
D	2.90	3.00	3.10	0.114	0.118	0.122		
Е	6.20	6.40	6.60	0.244	0.252	0.260		
E1	4.30	4.40	4.50	0.169	0.173	0.177		
е		0.65			0.0256			
k	0°		8°	0°		8°		
L	0.45	0.60	0.75	0.018	0.024	0.030		
L1		1			0.039			
aaa		0.1			0.004			

8 Ordering information

Table 8: Order codes

Order code	Temperature range	Package	Packaging	Marking
LM158QT	55 °C to 405 °C	DFN8 2x2		K4A
LM158DT	-55 °C to 125 °C	SO8		158
LM258ADT		SO8		258A
LM258AYDT ⁽¹⁾		SO8, automotive grade		258AY
LM258DT	-40 °C to 105 °C	SO8		258
LM258APT		TSSOP8		258A
LM258AST		MiniSO8		K408
LM258QT		DFN8 2x2	Tape and reel	K4C
LM358DT		SO8	- Tape and reer	358
LM358YDT ⁽¹⁾		SO8, automotive grade		358Y
LM358ADT		SO8		358A
LM358PT	0 °C to 70 °C	0 °C to 70 °C		358
LM358APT		13301 0		358A
LM358ST		MiniSO8		K405
LM358AST		Willingoo		K404
LM358QT		DFN8 2x2		K4E

⁽¹⁾ Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q

9 Revision history

Table 9: Document revision history

Date	Revision	Changes		
01-Jul- 2003	1	First release.		
02-Jan-2005	2	R_{thja} and T_{j} parameters added in AMR Table 1: "Absolute maximum ratings".		
01-Jul-2005	3	ESD protection inserted in Table 1: "Absolute maximum ratings".		
05-Oct-2006	4	Added Figure 17: Phase margin vs. capacitive load.		
30-Nov-2006	5	Added missing ordering information.		
25-Apr-2007	6	Removed LM158A, LM258A and LM358A from document title. Corrected error in MiniSO-8 package data. L1 is 0.004 inch. Added automotive grade order codes in Section 7: "Ordering information".		
12-Feb-2008	7	Corrected V_{CC} max (30 V instead of 32 V) in operating conditions. Changed presentation of electrical characteristics table. Deleted V_{opp} parameter in electrical characteristics table. Corrected miniSO-8 package information. Corrected temperature range for automotive grade order codes. Updated automotive grade footnotes in order codes table.		
26-Aug-2008	8	Added limitations on input current in Table 1: "Absolute maximum ratings". Corrected title for Figure 11. Added E and L1 parameters in Table 4: "SO8 package mechanical data". Changed Figure 31: "TSSOP8 package mechanical drawing".		
02-Sep-2011	9	In Section 6: "Package information", added: DFN8 2 x 2 mm package mechanical drawing DFN8 2 x 2 mm recommended footprint DFN8 2 x 2 mm order codes.		
06-Apr-2012	10	Removed order codes LM158YD, LM258AYD, LM258YD and LM358YD from Table 8: "Order codes".		
11-Jun-2013	11	Table 8: "Order codes": removed order codes LM158D, LM158YDT, LM258YDT, and LM258AD; added automotive grade qualification to order codes LM258ATDT and LM358YDT; updated marking for order codes LM158DT and LM258D/LM258DT; updated temperature range, packages, and packaging for several order codes.		
20-Jun-2014	12	Removed DIP8 package Corrected typos (W replaced with Ω, £ replaced with ≤) Updated Features Added Related products Table 3: replaced DV _{io} with ΔV _{io} /ΔT and DI _{io} with ΔI _{io} /ΔT. Updated Table 7 for exposed pad dimensions Table 8: "Order codes": removed order codes LM258YPT and LM258AYPT; removed all order codes for devices with tube packing; added package code (NB) to DFN8 2x2 package.		

Date	Revision	Changes
13-Nov-2015	13	Updated document layout Updated name of the "DFN8 2x2 (NB) mm" package to "DFN8 2x2" everywhere in datasheet. Section 2: "Package pin connections": placed the package's pinout in this section and added note about exposed pad. Table 8: "Order codes": removed order codes LM258ST, LM358YPT, and LM358AYPT.

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